# Functional Safety Information

# **TPS1663**

# Functional Safety FIT Rate, FMD and Pin FMA



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#### 1 Overview

This document contains information for TPS1663 (VQFN and HTSSOP package) to aid in a functional safety system design. Information provided are:

- Functional Safety Failure In Time (FIT) rates of the semiconductor component estimated by the application of industry reliability standards
- Component failure modes and their distribution (FMD) based on the primary function of the device
- Pin failure mode analysis (Pin FMA)

Figure 1-1 shows the device functional block diagram for reference.

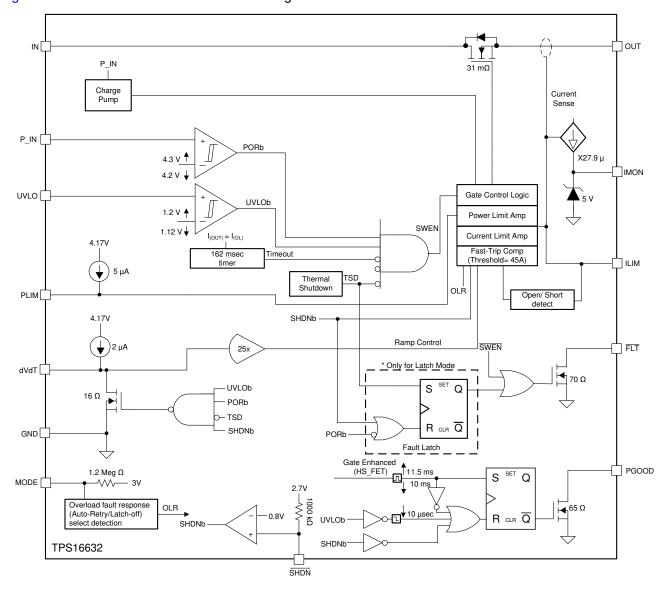


Figure 1-1. Functional Block Diagram

TPS1663 was developed using a quality-managed development process, but was not developed in accordance with the IEC 61508 or ISO 26262 standards.



# 2 Functional Safety Failure In Time (FIT) Rates

# 2.1 VQFN Package

This section provides Functional Safety Failure In Time (FIT) rates for VQFN package of TPS1663 based on two different industry-wide used reliability standards:

- Table 2-1 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-2 provides FIT rates based on the Siemens Norm SN 29500-2

Table 2-1. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

FIT IEC TR 62380 / ISO 26262	FIT (Failures Per 10 <sup>9</sup> Hours)
Total Component FIT Rate	17
Die FIT Rate	6
Package FIT Rate	11

The failure rate and mission profile information in Table 2-1 comes from the Reliability data handbook IEC TR 62380 / ISO 26262 part 11:

Mission Profile: Motor Control from Table 11

Power dissipation: 700 mW
Climate type: World-wide Table 8
Package factor (lambda 3): Table 17b

Substrate Material: FR4
 EOS FIT rate assumed: 0 FIT

Table 2-2. Component Failure Rates per Siemens Norm SN 29500-2

Table	Category	Reference FIT Rate	Reference Virtual T <sub>J</sub>
5	CMOS, BICMOS Digital, analog / mixed	25 FIT	55°C

The Reference FIT Rate and Reference Virtual T<sub>J</sub> (junction temperature) in Table 2-2 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



#### 2.2 HTSSOP Package

This section provides Functional Safety Failure In Time (FIT) rates for the HTSSOP package of TPS1663 based on two different industry-wide used reliability standards:

- Table 2-3 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-4 provides FIT rates based on the Siemens Norm SN 29500-2

Table 2-3. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

FIT IEC TR 62380 / ISO 26262	FIT (Failures Per 10 <sup>9</sup> Hours)
Total Component FIT Rate	18
Die FIT Rate	6
Package FIT Rate	12

The failure rate and mission profile information in Table 2-3 comes from the Reliability data handbook IEC TR 62380 / ISO 26262 part 11:

Mission Profile: Motor Control from Table 11

Power dissipation: 700 mW

Climate type: World-wide Table 8Package factor (lambda 3): Table 17b

Substrate Material: FR4

EOS FIT rate assumed: 0 FIT

Table 2-4. Component Failure Rates per Siemens Norm SN 29500-2

Table	Category	Reference FIT Rate	Reference Virtual T <sub>J</sub>
5	CMOS, BICMOS Digital, analog / mixed	25 FIT	55°C

The Reference FIT Rate and Reference Virtual  $T_J$  (junction temperature) in Table 2-4 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



# 3 Failure Mode Distribution (FMD)

The failure mode distribution estimation for TPS1663 in Table 3-1 comes from the combination of common failure modes listed in standards such as IEC 61508 and ISO 26262, the ratio of sub-circuit function size and complexity and from best engineering judgment.

The failure modes listed in this section reflect random failure events and do not include failures due to misuse or overstress.

Table 3-1. Die Failure Modes and Distribution

Die Failure Modes	Failure Mode Distribution (%)
OUT HIZ or no output	35%
OUT not in specification – voltage or timing	40%
IMON not in specification – current or timing	5%
PLIM not in specification – power or timing	5%
PGOOD/FLT fails to trip or false trip	5%
OUT stuck on	5%
Short circuit any two pins	5%



## 4 Pin Failure Mode Analysis (Pin FMA)

This section provides a Failure Mode Analysis (FMA) for the pins of the TPS1663 (VQFN and HTSSOP package). The failure modes covered in this document include the typical pin-by-pin failure scenarios:

- Pin short-circuited to Ground (see Table 4-2 and Table 4-6.)
- Pin open-circuited (seeTable 4-3 and Table 4-7)
- Pin short-circuited to an adjacent pin (see Table 4-4 and Table 4-8)
- Pin short-circuited to supply (see Table 4-5 and Table 4-9)

Table 4-2 through Table 4-9 also indicate how these pin conditions can affect the device as per the failure effects classification in Table 4-1.

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Class	Failure Effects	
A	Potential device damage that affects functionality	
В	No device damage, but loss of functionality	
С	No device damage, but performance degradation	
n	No device damage, no impact to functionality or performance	

Table 4-1. TI Classification of Failure Effects

Following are the assumptions of use and the device configuration assumed for the pin FMA in this section:

- · Capacitors are installed on IN and OUT pins.
- · Resistor is installed on ILIM pin.
- Resistors are installed on UVLO and OVP pin to set the UVLO and OVP set-points.

#### 4.1 VQFN Package

Figure 4-1 shows the TPS1663 pin diagram for the VQFN package. For a detailed description of the device pins please refer to the *Pin Configuration and Functions* section in the TPS1663 data sheet.

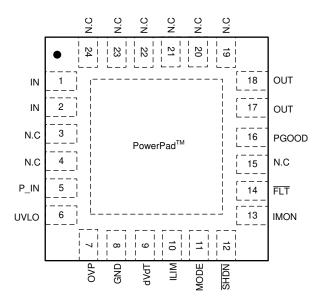


Figure 4-1. TPS16630 Pin Diagram (VQFN) Package

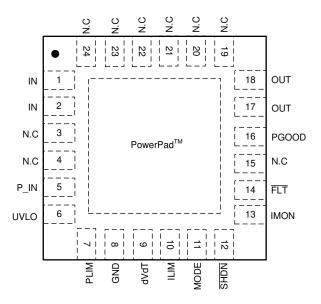


Figure 4-2. TPS16632 Pin Diagram (VQFN) Package

#### Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1,2	Device unpowered. Device not functional.	В
NC	3, 4, 15, 19, 20, 21, 22, 23, 24	No effect. Normal operation.	D
P_IN	5	Device unpowered. Device not functional.	В
UVLO	6	UVLO protection is triggered. Device turns off the internal FET.	В
OVP or PLIM	7	Over-voltage protection or power limiting will not function.	В
GND	8	No effect. Normal operation.	D
dVdT	9	Device doesn't power up.	В
ILIM	10	Device doesn't power up.	В
MODE	11	Device provides auto-retry behavior for over-current events as per device functional modes in data sheet.	D
SHDN	12	Device is disabled.	В
IMON	13	Current monitor function is not available.	В
FLT	14	Fault function is not available.	В
PGOOD	16	PGOOD function is not available.	В
OUT	17, 18	Device will enter into current limiting operation.	В



## Table 4-3. Pin FMA for Device Pins Open-Circuited

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1,2	Device unpowered. Device is not functional.	В
NC	3, 4, 15, 19, 20, 21, 22, 23, 24	No effect. Normal operation.	D
P_IN	5	Device unpowered. Device is not functional.	В
UVLO	6	Device functionality undetermined. Device may turn off / power down.	В
OVP or PLIM	7	TPS16630: over-voltage protection function is not determined.  Device may turn off the internal FET. TPS16632: output power limit is set to power more than 400 W.	В
GND	8	Device unpowered. Device is not functional.	В
dVdT	9	Device provides slew rate 24 V/500 µs on output.	D
ILIM	10	Internal FET is turned off. Output is not powered up.	В
MODE	11	Device provides latch-off behavior for over-current events as per device functional modes in data sheet.	D
SHDN	12	No effect. Normal operation.	D
IMON	13	No effect. Normal operation.	D
FLT	14	No effect. Normal operation.	D
PGOOD	16	No effect. Normal operation.	D
OUT	17, 18	No power or current provided to load.	D

## Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

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Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1,2	IN to NC: no effect. Normal operation.	D
NC	3, 4, 15, 19, 20, 21, 22, 23, 24	NC to P_IN: no effect. Normal operation.	D
P_IN	5	P_IN to UVLO: under-voltage protection will not function.	В
UVLO	6	UVLO to OVP/PLIM: potential device damage if UVLO voltage is more than 5.5 V.	Α
OVP or PLIM	7	OVP/PLIM to GND: over-voltage protection or Power limiting will not function.	В
GND	8	GND to dVdT: device unpowered. Device not functional.	В
dVdT	9	dVdT to ILIM: device can go into current limit operation.	В
ILIM	10	ILIM to MODE: device can go into current limit operation or Latch-off mode.	В
MODE	11	MODE to SHDN: device can go into shutdown.	В
SHDN	12	SHDN to IMON: device can go into shutdown.	В
IMON	13	IMON to FLT: potential Device damage if FLT pin voltage is more than 5.5 V.	А
FLT	14	PGOOD to FLT: oring of PGOOD and FLT signals.	D
PGOOD	16	PGOOD to OUT: potential device damage when PGOOD is low and output is powered up.	А
OUT	17, 18	OUT to N.C: no effect. Normal operation.	D



Table 4-5. Pin FMA for Device Pins Short-Circuited to IN or P\_IN

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1,2	No effect. Normal operation.	D
NC	3, 4, 15, 19, 20, 21, 22, 23, 24	No effect. Normal operation.	D
P_IN	5	No effect. Normal operation.	D
UVLO	6	Under-voltage protection will not function.	В
OVP or PLIM	7	Potential device damage if supply voltage is more than 5.5 V.	D
GND	8	Short circuit of input supply.	В
dVdT	9	Potential device damage if supply voltage is more than 5.5 V.	A
ILIM	10	Potential device damage if supply voltage is more than 5.5 V.	A
MODE	11	Potential device damage if supply voltage is more than 5.5 V.	A
SHDN	12	Potential device damage if supply voltage is more than 5.5 V.	A
IMON	13	Potential device damage if supply voltage is more than 5.5 V.	A
FLT	14	Potential device damage if FLT pin is low.	A
PGOOD	16	Potential device damage if PGOOD pin is low.	A
OUT	17, 18	Device will not limit power or current into load.	В



## 4.2 HTSSOP Package

Figure 4-3 shows the TPS1663 pin diagram for the HTSSOP package. For a detailed description of the device pins please refer to the *Pin Configuration and Functions* section in the TPS1663 data sheet.

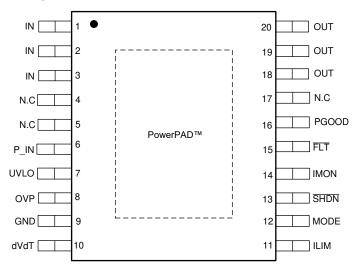


Figure 4-3. Pin Diagram (HTSSOP Package)

Table 4-6. Pin FMA for Device Pins Short-Circuited to Ground

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1, 2, 3	Device unpowered. Device not functional.	В
NC	4, 5, 17	No effect. Normal operation.	D
P_IN	6	Device unpowered. Device not functional.	В
UVLO	7	UVLO protetion is triggered. Device turns off the internal FET.	В
OVP	8	Over-voltage protection will not function.	В
GND	9	No effect. Normal operation.	D
dVdT	10	Device doesn't power up.	В
ILIM	11	Device doesn't power up.	В
MODE	12	Device provides auto-retry behavior for over-current events as per device functional modes in data sheet.	D
SHDN	13	Device is disabled.	В
IMON	14	Current monitor function is not available.	В
FLT	15	Fault function not available.	В
PGOOD	16	PGOOD function not available.	В
OUT	18, 19, 20	Device will enter into current limiting operation.	В

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Table 4-7. Pin FMA for Device Pins Open-Circuited

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1, 2, 3	Device unpowered. Device not functional.	В
NC	4, 5, 17	No effect. Normal operation.	D
P_IN	6	Device unpowered. Device not functional.	В
UVLO	7	Device functionality undetermined. Device may turn off / power down.	В
OVP	8	Over-voltage protection function is not determined. Device may turn off the internal FET.	В
GND	9	Device unpowered. Device not functional.	В
dVdT	10	Device provides slew rate 24 V/500 µs on output at power up.	D
ILIM	11	Internal FET is turned off. Output is not powered up.	В
MODE	12	Device provides latch-off behavior for over-current events as per device functional modes in data sheet.	D
SHDN	13	No effect. Normal operation.	D
IMON	14	No effect. Normal operation.	D
FLT	15	No effect. Normal operation.	D
PGOOD	16	No effect. Normal operation.	D
OUT	18, 19, 20	No power or current provided to load.	D

Table 4-8. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1, 2, 3	IN to NC: no effect. Normal operation.	D
NC	4, 15, 17	NC to P_IN: no effect. Normal operation.	D
P_IN	6	P_IN to UVLO: under-voltage protection will not function.	В
UVLO	7	UVLO to OVP: potential device damage if UVLO voltage is more than 5.5 V.	В
OVP	8	OVP to GND: over-voltage protection will not function.	В
GND	9	GND to dVdT: device unpowered. Device not functional.	В
dVdT	10	dVdT to ILIM: device can go into current limit operation.	В
ILIM	11	ILIM to MODE: device can go into current limit operation or Latch-off mode.	В
MODE	12	MODE to SHDN: device can go into shutdown.	В
SHDN	13	SHDN to IMON: device can go into shutdown.	В
IMON	14	IMON to FLT: potential Device damage if FLT pin voltage is more than 5.5 V.	А
FLT	15	PGOOD to FLT: oring of PGOOD and FLT signals.	D
PGOOD	16	PGOOD to OUT: potential device damage when PGOOD is low and output is powered up.	А
OUT	18, 19, 20	OUT to N.C: no effect. Normal operation.	D



# Table 4-9. Pin FMA for Device Pins Short-Circuited to IN or P\_IN

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
IN	1,2	No effect. Normal operation.	D
NC	3, 4, 17	No effect. Normal operation.	D
P_IN	6	No effect. Normal operation.	D
UVLO	7	Under-voltage protection will not function.	В
OVP	8	Potential device damage if supply voltage is more than 5.5 V	D
GND	9	Short circuit of input supply.	В
dVdT	10	Potential device damage if supply voltage is more than 5.5 V.	A
ILIM	11	Potential device damage if supply voltage is more than 5.5 V.	A
MODE	12	Potential device damage if supply voltage is more than 5.5 V.	A
SHDN	13	Potential device damage if supply voltage is more than 5.5 V.	A
IMON	14	Potential device damage if supply voltage is more than 5.5 V.	A
FLT	15	Potential device damage if FLT pin is low.	A
PGOOD	16	Potential device damage if PGOOD pin is low.	A
OUT	18, 19, 20	Device will not limit power or current into load.	В

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